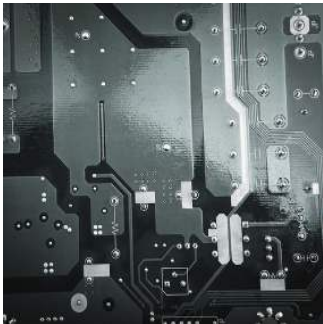


## 2SB886 Darlington BJT



Datasheet: [View](#)

|                          |      |
|--------------------------|------|
| Stock                    |      |
| NEW JERSEY SEMICONDUCTOR | 1400 |
| SANYO                    | 45   |

Trans Darlington PNP 100V 8A 3-Pin(3+Tab) TO-220AB

[Request For Quote](#)

[Datasheet](#)

| Features                                | Values     | Unit |
|---|------------|------|
| Typical Current Gain Bandwidth          | 20         | MHz  |
| Type                                    | PNP        |      |
| Number of Elements per Chip             | 1          |      |
| Minimum Operating Temperature           | -55        | °C   |
| Minimum DC Current Gain                 | 1500@4A@3V |      |
| Maximum Operating Temperature           | 150        | °C   |
| Maximum Emitter Base Voltage            | 6          | V    |
| Maximum Continuous DC Collector Current | 8          | A    |
| Maximum Collector Emitter Voltage       | 100        | V    |
| Maximum Collector Base Voltage          | 110        | V    |
| Maximum Base Emitter Saturation Voltage | 2@8mA@4A   | V    |
| Configuration                           | Single     |      |

[JOIN OUR MAILING LIST](#)

COMPANY

[About Us](#)

[Distributors](#)

[Request for quote](#)

[Contact Us](#)



Connect with us!

**New Jersey Semiconductor**

Providing parts at your convenience.

20 Stern Ave

Springfield, NJ 07081

P: (973)376-2922

Fax: (973)376-8960

Email

Copyright 2016 New Jersey Semiconductor. All rights reserved.